

Output inverter application

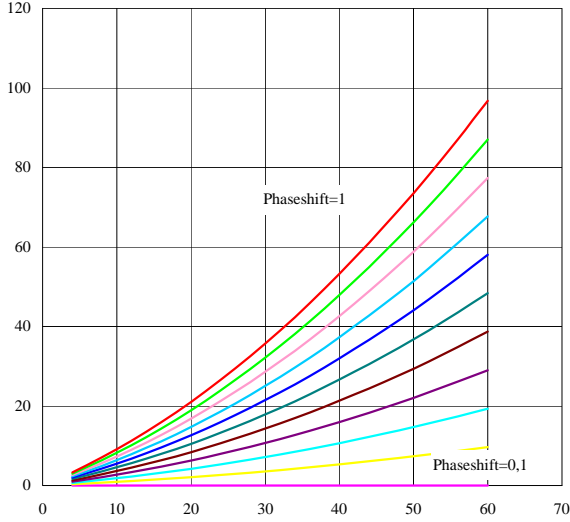
 Phase shifted ZVS, $V_{geon}= 15\text{ V}$ $V_{geoff}=0\text{V}$ $R_{gon}= 4\text{ ohms}$ $R_{goff}= 2\text{ ohms}$
Figure 1. Typical static loss of shifted switch as a function of output current
IGBT $P_{loss}=f(I_{out})$

 Conditions: $T_j=125^\circ\text{C}$
 Phaseshift parameter Phaseshift from 0,10 to 1,00 in 0,10 steps

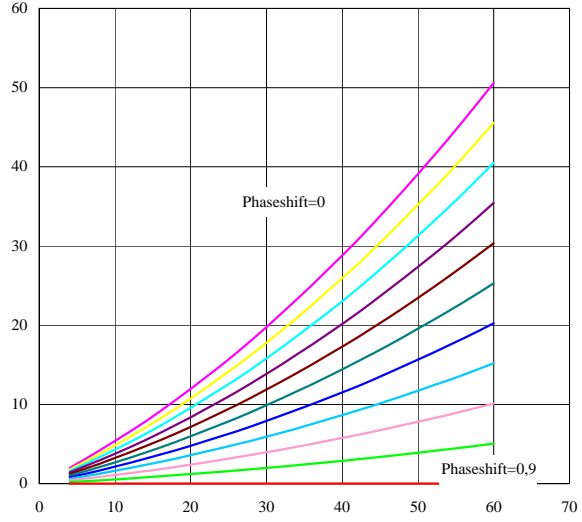
Figure 2. Typical static loss of shifted switch as a function of output current
FRED $P_{loss}=f(I_{out})$

 Conditions: $T_j=125^\circ\text{C}$
 Phaseshift parameter Phaseshift from 0,00 to 0,90 in 0,10 steps

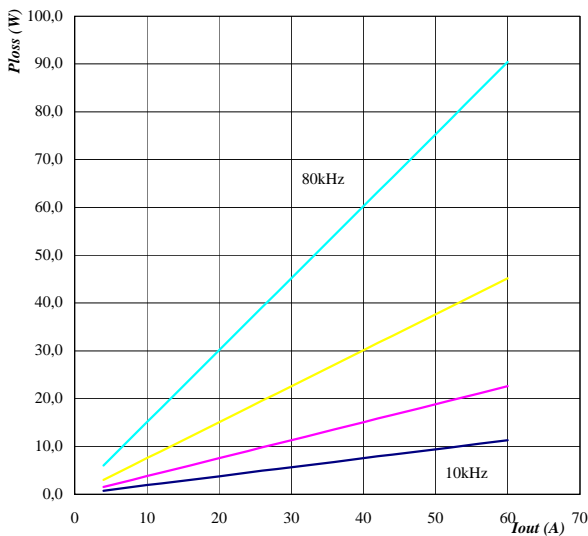
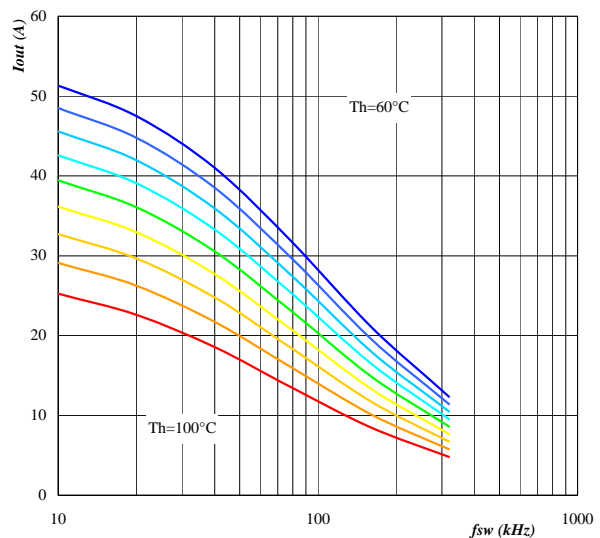
Figure 3. Typical switching loss as a function of output current
IGBT $P_{loss}=f(I_{out})$

 Conditions: $T_j=125^\circ\text{C}$
 $I_{outpk}/I_{out}= 1,3$ DC link= 300 V
 Phaseshift= 1
 Switching freq. parameter fsw from 10 kHz to 80 kHz in * 2 steps

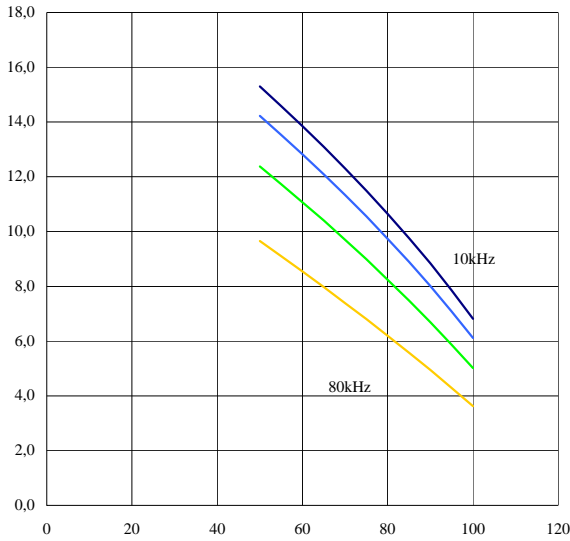
Figure 4. Typical available output current as a function of switching frequency
Phase $I_{out}=f(f_{sw})$

 Conditions: $T_j=125^\circ\text{C}$
 $I_{outpk}/I_{out}= 1,3$ DC link= 300 V
 Phaseshift= 1
 Heatsink temp. parameter T_h from 60 °C to 100 °C in 5 °C steps

Output inverter application

Phase shifted ZVS, $V_{geon}= 15\text{ V}$ $V_{geoff}=0\text{V}$ $R_{gon}= 4\text{ ohms}$ $R_{goff}= 2\text{ ohms}$

Figure 5. Typical available electric peak output power as a function of heatsink temperature

Inverter $P_{out}=f(T_h)$

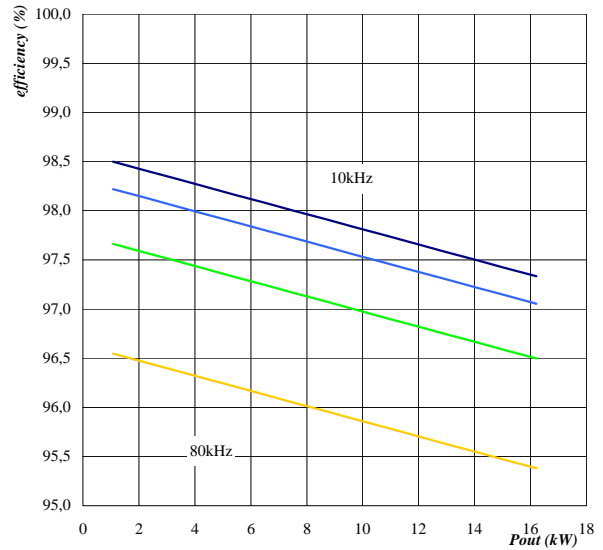


Conditions: $T_j=125\text{C}$
 $I_{outpk}/I_{out}= 1,3$ DC link= 300 V
 Phaseshift= 1

Switching freq. parameter fsw from in 10 kHz to 80 kHz * 2 steps

Figure 6. Typical efficiency as a function of output power

Inverter efficiency=f(P_{out})



Conditions: $T_j=125\text{C}$
 $I_{outpk}/I_{out}= 1,3$ DC link= 300 V
 Phaseshift= 1

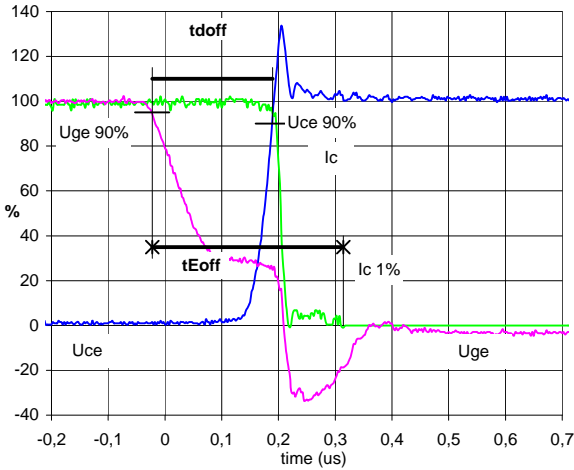
Switching freq. parameter fsw from in 10 kHz to 80 kHz * 2 steps

Switching definitions

General conditions: $T_j = 125\text{ }^\circ\text{C}$

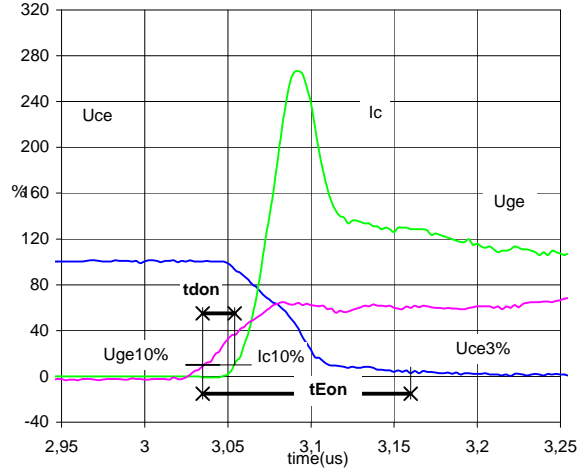
$R_{gon} = 4\text{ ohms}$ $R_{goff} = 2,0\text{ ohms}$

Figure 1. Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff}
 (t_{Eoff} = integrating time for E_{off})
 Output inverter IGBT



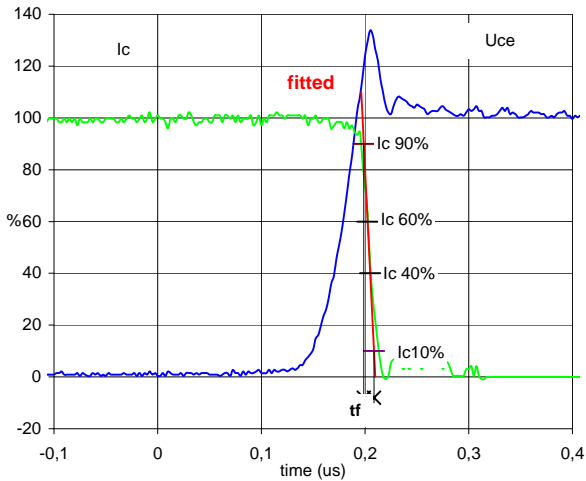
$U_{ge}(0\%) = 0\text{ V}$
 $U_{ge}(100\%) = 15\text{ V}$
 $U_c(100\%) = 400\text{ V}$
 $I_c(100\%) = 60\text{ A}$
 $t_{doff} = 0,21\text{ }\mu\text{s}$
 $t_{Eoff} = 0,34\text{ }\mu\text{s}$

Figure 2. Turn-on Switching Waveforms & definition of t_{don} , t_{Eon}
 (t_{Eon} = integrating time for E_{on})
 Output inverter IGBT



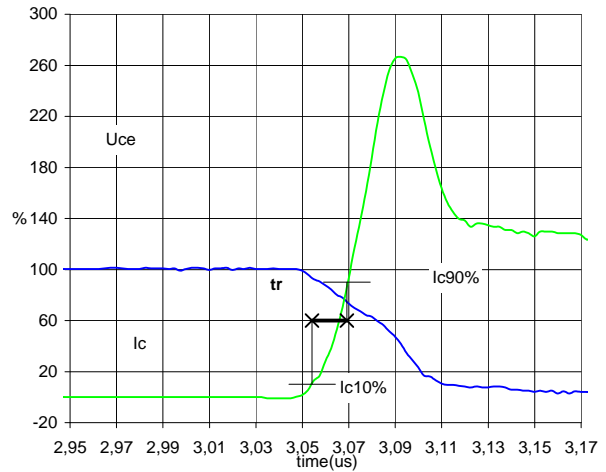
$U_{ge}(0\%) = 0\text{ V}$
 $U_{ge}(100\%) = 15\text{ V}$
 $U_c(100\%) = 400\text{ V}$
 $I_c(100\%) = 59,7\text{ A}$
 $t_{don} = 0,02\text{ }\mu\text{s}$
 $t_{Eon} = 0,12\text{ }\mu\text{s}$

Figure 3. Turn-off Switching Waveforms & definition of t_f
 Output inverter IGBT



$U_c(100\%) = 400\text{ V}$
 $I_c(100\%) = 60\text{ A}$
 $t_f = 0,012\text{ }\mu\text{s}$

Figure 4. Turn-on Switching Waveforms & definition of t_r
 Output inverter IGBT



$U_c(100\%) = 400\text{ V}$
 $I_c(100\%) = 59,7\text{ A}$
 $t_r = 0,016\text{ }\mu\text{s}$

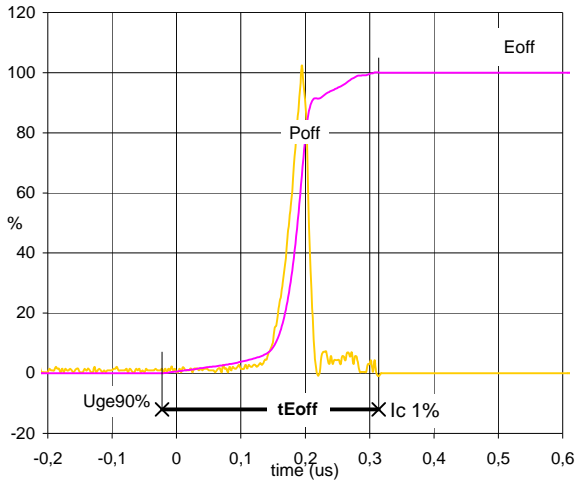
Switching definitions

General conditions: $T_j = 125\text{ }^\circ\text{C}$

$R_{gon} = 4\text{ ohms}$ $R_{goff} = 2,0\text{ ohms}$

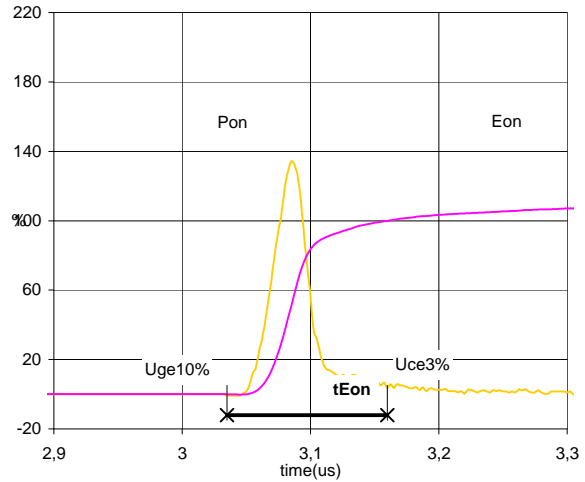
Switching definitions

Figure 5. Turn-off Switching Waveforms & definition of t_{Eoff}
Output inverter IGBT



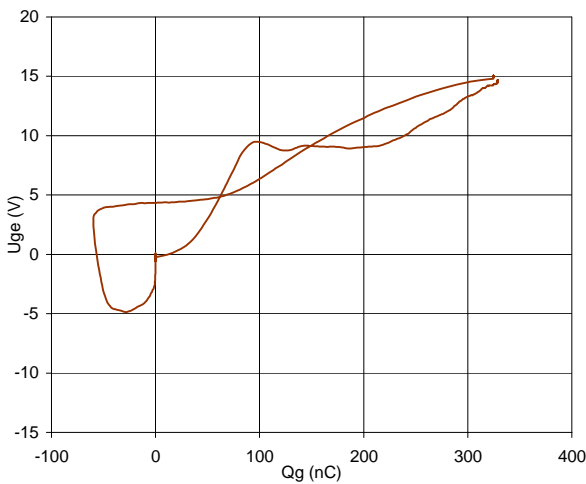
$P_{off}(100\%) = 23,88\text{ kW}$
 $E_{off}(100\%) = 0,97\text{ mJ}$
 $t_{Eoff} = 0,34\text{ }\mu\text{s}$

Figure 6. Turn-on Switching Waveforms & definition of t_{Eon}
Output inverter IGBT



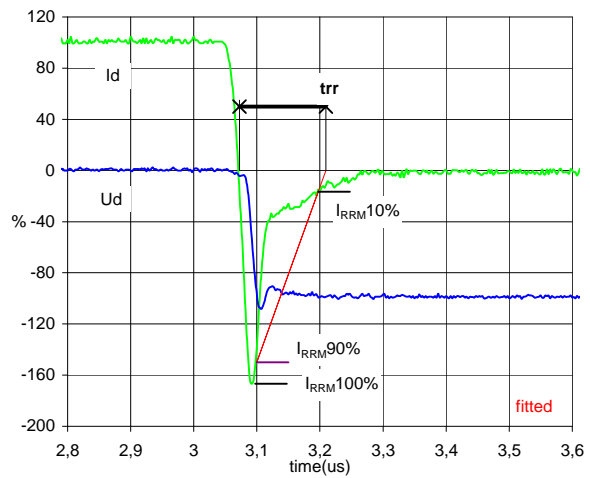
$P_{on}(100\%) = 23,9\text{ kW}$
 $E_{on}(100\%) = 1,11\text{ mJ}$
 $t_{Eon} = 0,12\text{ }\mu\text{s}$

Figure 7. Gate voltage vs Gate charge
Output inverter IGBT



$U_{geoff} = 0\text{ V}$
 $U_{geon} = 15\text{ V}$
 $U_{c}(100\%) = 400\text{ V}$
 $I_{c}(100\%) = 60\text{ A}$
 $Q_g = 328,7\text{ nC}$

Figure 8. Turn-off Switching Waveforms & definition of t_{rr}
Output inverter FRED

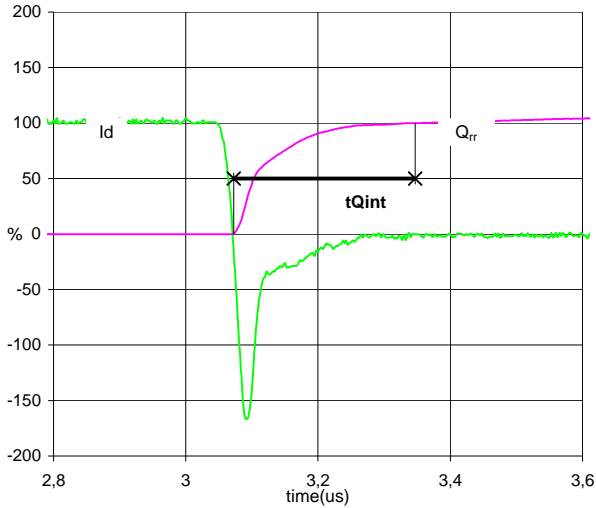


$U_d(100\%) = 400\text{ V}$
 $I_d(100\%) = 59,7\text{ A}$
 $I_{RRM}(100\%) = 100\text{ A}$
 $t_{rr} = 0,13\text{ }\mu\text{s}$

Switching definitions

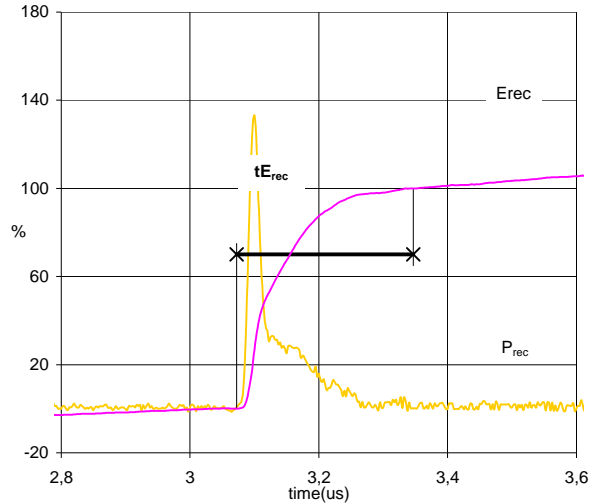
 General conditions: $T_j = 125\text{ }^\circ\text{C}$
 $R_{gon} = 4\text{ ohms}$ $R_{goff} = 2,0\text{ ohms}$
Switching definitions

Figure 9. Turn-on Switching Waveforms & definition of t_{Qrr}
 (t_{Qrr} = integrating time for Q_{rr})
 Output inverter FRED



$I_d(100\%) = 60\text{ A}$
 $Q_{rr}(100\%) = 4,492\text{ }\mu\text{C}$
 $t_{Qint} = 0,27\text{ }\mu\text{s}$

Figure 10. Turn-on Switching Waveforms & definition of t_{Erec}
 (t_{Erec} = integrating time for E_{rec})
 Output inverter FRED



$P_{rec}(100\%) = 23,9\text{ kW}$
 $E_{rec}(100\%) = 1,32\text{ mJ}$
 $t_{Erec} = 0,27\text{ }\mu\text{s}$